# **ON Semiconductor**

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# **Power MOSFET**

# 24 V, 80 A, N-Channel DPAK

Designed for low voltage, high speed switching applications in power supplies, converters and power motor controls and bridge circuits.

#### **Features**

• These Devices are Pb-Free and are RoHS Compliant

### **Typical Applications**

- Power Supplies
- Converters
- Power Motor Controls
- Bridge Circuits

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	$V_{DSS}$	24	Vdc
Gate-to-Source Voltage - Continuous	V <sub>GS</sub>	±20	Vdc
Drain Current – Continuous @ $T_C$ = 25°C – Single Pulse ( $t_p$ = 10 $\mu$ s)	I <sub>D</sub> I <sub>DM</sub>	80* 200	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C	$P_{D}$	75	Watts
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C
Single Pulse Drain-to-Source Avalanche Energy – Starting $T_J$ = 25°C ( $V_{DD}$ = 24 Vdc, $V_{GS}$ = 10 Vdc, $I_L$ = 17 Apk, $L$ = 5.0 mH, $R_G$ = 25 $\Omega$ )	E <sub>AS</sub>	733	mJ
Thermal Resistance  – Junction-to-Case  – Junction-to-Ambient (Note 1)  – Junction-to-Ambient (Note 2)	$egin{array}{c} R_{ heta JC} \ R_{ heta JA} \ R_{ heta JA} \end{array}$	1.65 67 120	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	TL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. When surface mounted to an FR4 board using 1" pad size, (Cu Area 1.127 in<sup>2</sup>).
- 2. When surface mounted to an FR4 board using the minimum recommended pad size, (Cu Area 0.412 in<sup>2</sup>).

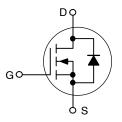


### ON Semiconductor®

#### http://onsemi.com

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> TYP	I <sub>D</sub> MAX
24 V	$5.0~\text{m}\Omega$	80 A

### N-Channel



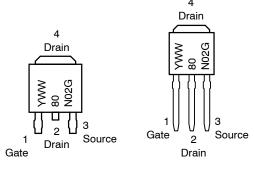






CASE 369AA CASE 369C CASE 369D DPAK **DPAK** DPAK (Surface Mount) (Surface Mount) (Straight Lead) STYLE 2 STYLE 2 STYLE 2

### **MARKING DIAGRAMS** & PIN ASSIGNMENTS



80N02 = Device Code Υ = Year WW = Work Week = Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

<sup>\*</sup>Chip current capability limited by package.

# **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ unless otherwise noted)

Chai	Symbol	Min	Тур	Max	Unit		
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Volta $(V_{GS}=0~Vdc,~I_D=250~\mu Adc)$ Positive Temperature Coefficient	V <sub>(BR)DSS</sub>	24 -	27 25	- -	Vdc mV/°C		
Zero Gate Voltage Drain Current $(V_{GS} = 0 \text{ Vdc}, V_{DS} = 24 \text{ Vdc})$ $(V_{GS} = 0 \text{ Vdc}, V_{DS} = 24 \text{ Vdc}, T_J$	I <sub>DSS</sub>	_ _	- -	1.0 10	μAdc		
Gate-Body Leakage Current (V <sub>GS</sub>	$= \pm 20 \text{ Vdc}, \text{ V}_{DS} = 0 \text{ Vdc})$	I <sub>GSS</sub>	-	-	±100	nAdc	
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage (Note 3) $(V_{DS} = V_{GS}, I_D = 250 \mu\text{Adc})$ Negative Threshold Temperature C	V <sub>GS(th)</sub>	1.0	1.9 -3.8	3.0	Vdc mV/°C		
Static Drain-to-Source On-Resist $(V_{GS} = 10 \text{ Vdc}, I_D = 80 \text{ Adc})$ $(V_{GS} = 4.5 \text{ Vdc}, I_D = 40 \text{ Adc})$ $(V_{GS} = 10 \text{ Vdc}, I_D = 20 \text{ Adc})$ $(V_{GS} = 4.5 \text{ Vdc}, I_D = 20 \text{ Adc})$	R <sub>DS(on)</sub>	- - -	5.0 7.5 5.0 7.5	5.8 9.0 5.8 9.0	mΩ		
Forward Transconductance (V <sub>DS</sub> =	15 Vdc, I <sub>D</sub> = 10 Adc) (Note 3)	9FS	_	20	-	Mhos	
DYNAMIC CHARACTERISTICS							
Input Capacitance	(V <sub>DS</sub> = 20 Vdc,	C <sub>iss</sub>	_	2250	2600	pF	
Output Capacitance	$V_{GS} = 0 V$	C <sub>oss</sub>	_	900	1100		
Transfer Capacitance	f = 1.0 MHz)	C <sub>rss</sub>	_	400	525		
SWITCHING CHARACTERISTICS (	Note 4)						
Turn-On Delay Time	(V <sub>GS</sub> = 4.5 Vdc,	t <sub>d(on)</sub>	_	17	30	ns	
Rise Time	$V_{DD} = 20 \text{ Vdc},$	t <sub>r</sub>	-	67	125		
Turn-Off Delay Time	I <sub>D</sub> = 20 Adc,	t <sub>d(off)</sub>	-	28	45		
Fall Time	$R_G = 2.5 \Omega$ )	t <sub>f</sub>	_	40	75		
Gate Charge	(V <sub>GS</sub> = 4.5 Vdc,	Q <sub>T</sub>	_	30	42	nC	
	$I_D = 20 \text{ Adc},$	Q1	_	7.0	12	]	
	V <sub>DS</sub> = 20 Vdc) (Note 3)	Q2	_	18	28		
SOURCE-DRAIN DIODE CHARACT	TERISTICS						
Forward On–Voltage $ \begin{aligned} &(I_S=20 \text{ Adc, V}_{GS}=0 \text{ Vdc) (Note 3)} \\ &(I_S=40 \text{ Adc, V}_{GS}=0 \text{ Vdc)} \\ &(I_S=20 \text{ Adc, V}_{GS}=0 \text{ Vdc, T}_J=150^{\circ}\text{C)} \end{aligned} $		V <sub>SD</sub>	- - -	0.92 1.05 0.70	1.2 - -	Vdc	
Reverse Recovery Time		t <sub>rr</sub>	_	38	52	ns	
	$(I_S = 20 \text{ Adc}, V_{GS} = 0 \text{ Vdc}, \\ dI_S/dt = 100 \text{ A/}\mu\text{s}) \text{ (Note 3)}$	t <sub>a</sub>	-	20	-	]	
		t <sub>b</sub>	-	18	-	1	
Reverse Recovery Stored Charge	Q <sub>rr</sub>	_	0.038	_	μС		

Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
 Switching characteristics are independent of operating junction temperatures.

### **TYPICAL CHARACTERISTICS**

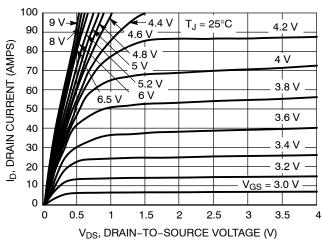


Figure 1. On-Region Characteristics

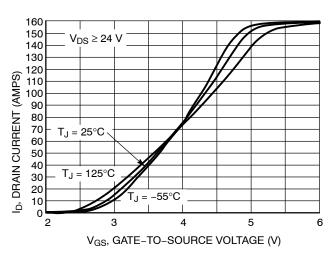


Figure 2. Transfer Characteristics

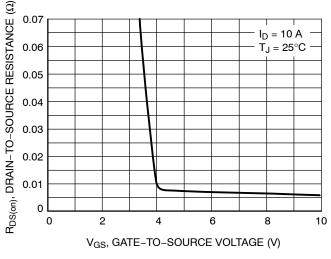


Figure 3. On-Resistance versus Gate-To-Source Voltage

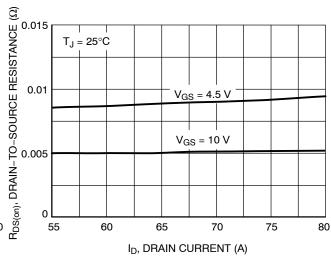


Figure 4. On-Resistance versus Drain Current and Gate Voltage

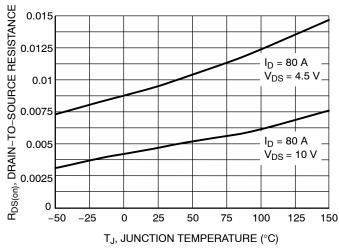


Figure 5. On–Resistance Variation with Temperature

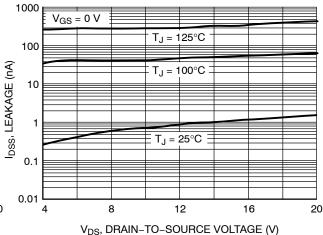


Figure 6. Drain-To-Source Leakage Current versus Voltage

#### **TYPICAL CHARACTERISTICS**

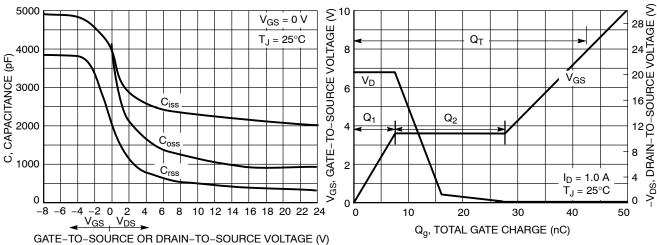


Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage versus Total Charge

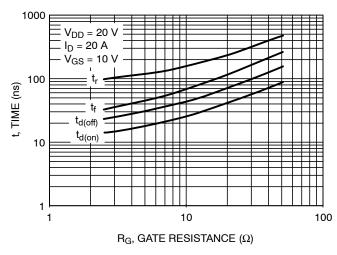
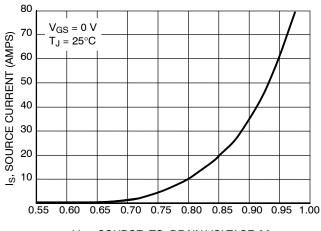


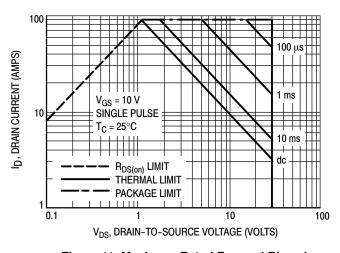
Figure 9. Resistive Switching Time Variation versus Gate Resistance



V<sub>SD</sub>, SOURCE-TO-DRAIN VOLTAGE (V)

Figure 10. Diode Forward Voltage versus Current

#### **TYPICAL CHARACTERISTICS**



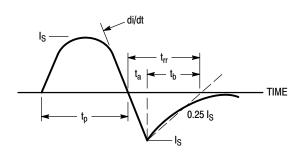


Figure 11. Maximum Rated Forward Biased Safe Operating Area

Figure 12. Diode Reverse Recovery Waveform

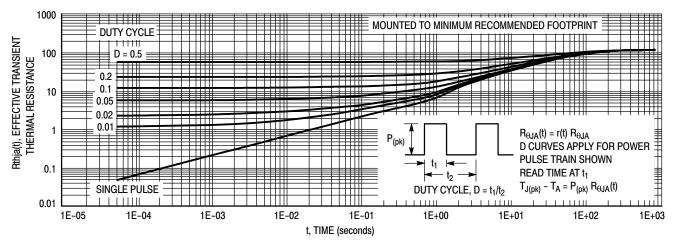


Figure 13. Thermal Response - Various Duty Cycles

#### **ORDERING INFORMATION**

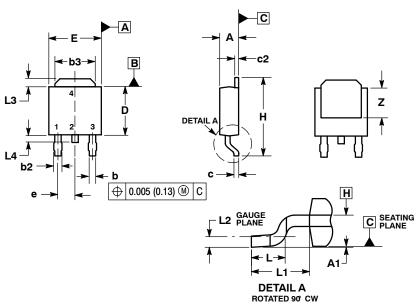
Order Number	Package	Shipping <sup>†</sup>
NTD80N02T4G	DPAK-3 (Pb-Free)	2500 / Tape & Reel
NTD80N02-1G	DPAK-3 Straight Lead (Pb-Free)	75 Units / Rail

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS

## **DPAK (SINGLE GAUGE)**

CASE 369AA-01 **ISSUE B** 



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

  2. CONTROLLING DIMENSION: INCHES.

  3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.

  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.

  5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.

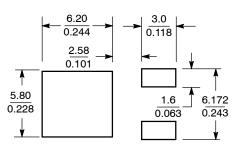
  6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.030	0.045	0.76	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
Е	0.250	0.265	6.35	6.73
e	0.090 BSC		2.29 BSC	
Η	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.108 REF		2.74 REF	
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Z	0.155		3.93	

STYLE 2: PIN 1. GATE 2. DRAIN 3. SOURCE

4. DRAIN

#### **SOLDERING FOOTPRINT\***



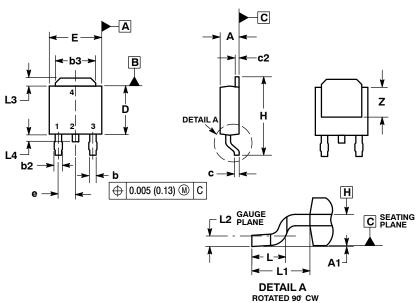
 $\left(\frac{\text{mm}}{\text{inches}}\right)$ SCALE 3:1

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **PACKAGE DIMENSIONS**

### **DPAK (SINGLE GAUGE)**

CASE 369C-01 ISSUE D



#### NOTES:

- NOTES:

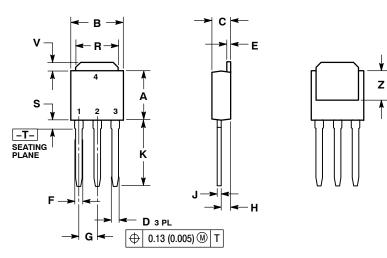
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: INCHES.
  3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.
  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
  5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
  6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.

	INCHES MIL		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.030	0.045	0.76	1.14
b3	0.180	0.215	4.57	5.46
С	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
е	0.090 BSC		2.29 BSC	
Н	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.108 REF		2.74 REF	
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4		0.040		1.01
Z	0.155		3.93	

- STYLE 2: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN

#### PACKAGE DIMENSIONS

#### **DPAK** CASE 369D-01 **ISSUE B**



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

	INCHES MILLIMET		IETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.245	5.97	6.35	
В	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
E	0.018	0.023	0.46	0.58	
F	0.037	0.045	0.94	1.14	
G	0.090	BSC	2.29 BSC		
Н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
K	0.350	0.380	8.89	9.65	
R	0.180	0.215	4.45	5.45	
S	0.025	0.040	0.63	1.01	
٧	0.035	0.050	0.89	1.27	
Z	0.155		3.93		

STYLE 2: PIN 1. GATE

- 2 DRAIN
- SOURCE
- DRAIN

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